

# **Automotive H-Bridge Driver**

- Operating Supply Voltage 5V to 28V
- Overvoltage Protection against Transients up to 40V at Vbat
- RDSon =  $150m\Omega$  for each Output Transistor at  $25^{\circ}C$
- Continous DC Load Current 5A (TC < 100°C)
- Output Current Limitation at typ 6,5A +/- 20%
- Short-Circuit Shutdown for Output Currents over 8A
- Logic Inputs TTL/CMOS Compatible
- Operating Frequency up to 20 kHz
- Overtemperature Protection
- Short-Circuit Protection
- Undervoltage Disable Function
- Diagnostic Output
- 2 Disable Inputs

SF

IN1 IN2

DI1

DI2

COD

- Coding Input for Alternative Functions
- HSOP20 Power Package
- $\bullet$  Stable Operation with an External Capacitance of maximum 47  $\mu F$  at Vbat





PIN CONNECTIONS					
AGND 1	0	20 NC			
SF 2		19 IN2			
IN1 3		18 DI1			
V <sub>bat</sub> 4		17 CP			
V <sub>bat</sub> 5		16 V <sub>bat</sub>			
OUT1 6		15 OUT2			
OUT1 7		14 OUT2			
COD 8		13 DI2			
PGND 9		12 PGND			
PGND 10		11 PGND			
Metal slug is connected to power ground					
(Top View)					

ORDERING INFORMATION						
Device	Temperature Range	Package				
MC33186DH1R2	-40°C to +125°C	HSOP20				

MC33186

## MAXIMUM RATINGS

Ratings	Symbol	Min	Тур	Мах	Unit
ELECTRICAL RATINGS					
Supply Voltage - Static Destruction Proof - Dynamic Destruction Proof t < 0,5s	Vbat Vbat	- 1 - 2		28 40	V
Logic Inputs (IN1, IN2, DI1, DI2, CODE)	U	- 0.5		7	V
Output Status - Flag SF	U <sub>SF</sub>	- 0.5		7	V
THERMAL RATINGS					
Junction Temperature	Тj	- 40		+150	°C
Storage Temperature	Τ <sub>s</sub>	- 55		+125	°C
Ambient Temperature	T <sub>a</sub>	- 40		+125	°C
Thermal Resistance (with power applied on 2 power MOS)	Rth <sub>JC</sub>			+1,5	K/W

# **ELECTRICAL CHARACTERISTICS.**Tj : from -40°C to +150 °C, Vbat from 5 V to 28 V, unless otherwise note. Typical values reflect approximate mean at 25°C, nominal VCC, at time of device characterization.

Characteristics	Symbol	Min	Тур	Мах	Unit	
RANGE OF VALIDITY						
	Vbat T <sub>j</sub>	5 -40		28 150	°C	
POWER SUPPLY						
Operating Range : - Static - Dynamic ( t < 500ms )	Vbat Vbat	5		28 40	V V	
Stanby current - f = 0 to 10KHz ; I <sub>OUT</sub> = 0A	l Vbat			35	mA	
Vbat-undervoltage switch-off (without load) - Switch-off Voltage - Switch-on Voltage - Hysteresis		4.15 4.5 150	4.4 4.75	4.65 5	V V mV	
CHARGE-PUMP SUPPLY					·	
- Vbat = 4.15 V - Vbat < 40V	Vcp - Vbat Vcp - Vbat	3.35		20	V V	
LOGIC INPUTS						
Input High	VinH	3.4			V	
Input Low	VinL			1.4	V	
Input Hysteresis	U	0.7	1		V	
Input Current (IN1, IN2, DI1) - U <sub>IN</sub> = 0V	I	- 200	- 80		μΑ	
Input Current (DI2,COD) - U <sub>DI2</sub> = 5V	I <sub>DI2</sub>		25	100	μΑ	

**ELECTRICAL CHARACTERISTICS.**Tj : from -40°C to +150 °C, Vbat from 5 V to 28 V, unless otherwise note. Typical values reflect approximate mean at 25°C, nominal VCC, at time of device characterization.

Characteristics	Symbol	Min	Тур	Мах	Unit
POWER OUTPUTS : OUT1, OUT2		-			
Switch on resistances : R <sub>OUT - Vbat</sub> ; R <sub>OUT - GND</sub>					
- Vbat =5 to 28V ; Ccp = 0 to 33nF				300	mΩ
Current Limitation Controlled Peak Value		-	L		
Switch-off Current	(I <sub>OUT</sub> ) max	5.2	6.5	7.8	А
Switch-off Time	ta	15	20.5	26	μs
Blanking Time	tb	12	16.5	21	μs
High Side Overcurrent Detection Low Side Overcurrent Detection (4)	I <sub>OCHS</sub> I <sub>OCLS</sub>	11 8			A A
Leackage Current - Output Stage Switched off				100	μΑ
Free-Wheeling Diode Forward Voltage - I <sub>OU</sub> = 3A	U <sub>D</sub>			2	V
Free-Wheeling Diode Reverse Recovery Time	trr	100			ns
- Switch-off Temperature - Hysteresis		160 20		190 30	°C ℃
OUTPUT STATUS FLAG (Open drain output)					
Output High (SF not set) U <sub>SF</sub> = 5V	I <sub>SF</sub>			10	μΑ
Output Low (SF set) ISF = 300 μA	VSF			1	V
TIMING					
PWM frequency - C <sub>CP</sub> = 33nF	f			10	KHz
Maximum Switching Frequency During Current Limitation - Vbat = 628VC <sub>CP</sub> = 33nF	f			20	KHz
Output ON Delay IN1 <sub>&gt;</sub> OUT1 or IN2 <sub>&gt;</sub> OUT2	t <sub>don</sub>			15	μs
Output OFF Delay IN1 <sub>&gt;</sub> OUT1 or IN2 <sub>&gt;</sub> OUT2	t <sub>doff</sub>			15	μs
Output Switching Time - C <sub>CP</sub> = 0 to 33nF OUTiHOUTiL, OUTiLOUTiH, IOUT= 3A	t <sub>r</sub> , t <sub>f</sub>	2		5	μs
Disable Delay Time DliOUTi	t <sub>ddis</sub>			8	μs
Turn off in Case of Over-current or Over-temperature			4		μs
Power On Delay Time (Ccp = 33nF)			1	5	ms

## **TRUH TABLE**

Device State	Input Conditions		Status		Outputs			
	DI1 (3)	DI2 (3)	IN1	IN2	SF (5)	SF (6)	OU1	OU2
1-Forward	L	Н	Н	L	Н	Н	н	L
2-Reverse	L	Н	L	Н	Н	Н	L	н
3-Free Wheeling Low	L	Н	L	L	Н	Н	L	L
4-Free Wheeling High	L	Н	Н	Н	Н	Н	н	н
5-Disable 1	Н	Х	Х	Х	L	Н	Z	Z
6-Disable 2	Х	L	Х	Х	L	Н	Z	Z
7-IN1 Disconnected	L	Н	Z	Х	Н	Н	н	х
8-IN2 Disconnected	L	Н	Х	Z	Н	Н	х	н
9-DI1 Disconnected	Z	Х	Х	Х	L	Н	Z	Z
10-DI2 Disconnected	Х	Z	Х	Х	L	Н	Z	Z
11-Current Limit.active	L	Н	Х	Х	Н	Н	Z	Z
12-Undervoltage (1)	Х	Х	Х	Х	L	L	Z	Z
13-Over-temperature (2)	Х	Х	Х	Х	L	L	Z	Z
14-Over-current (2)	х	Х	Х	х	L	L	Z	Z

#### NOTE :

(1) In case of undervoltage, tristate and status-flag are reset automatically.
(2) Whenever over-current or over-temperature is detected, the fault is stored (i.e.status-flag remains low). The tristate conditions and the status-flag are reset via DI1 (IN1) or DI2 (IN2).
Pinnames in brackets refer to coding pin (COD=Vcc).
(3) If COD = Vcc then DI1 and DI2 are not active.

(4) In case of over-current, the time when the current is greater than 7,8A is lower than 30µs, with a maximum frequency of 1kHz.

(5) COD=nc or GND (6) COD = VCC

L = Low H = High

X = High or LowZ = High impedance (all output stage transistors are switched off ).

## PINS FUNCTION DESCRIPTION

Pin	Name	Description
9, 10, 11, 12 Metal slug	GND	Power Ground
1	GND	Analog ground
2	Output Status- flag (SF)	Open drain output, active low. Is set according to the truth table .
3,13 18, 19	Inputs IN1,IN2 DI1,DI2, COD	Voltage controlled inputs with hysteresis
8	COD	When not connected or connected to GND, a stored failure will be reset by change of the voltage-level on DI1 or DI2. When connected to Vcc, the disable pin DI1 and DI2 are inactive. A stored failure will be reset by change of the voltage-level on IN1 or IN2.
6, 7, 14, 15	OUT1 , OUT2	H-Bridge outputs with integrated free-wheeling diodes.
4, 5, 16	Vbat	The pins 4 and 5 are internally connected. These pins supply the left high side and the analogue/logic part of the device. The pin 16 supplies the right high side and the charge pump. The pins 4, 5 and 16 should be connected together on the printed circuit board with connections as short as possible. <i>Supervision and protection functions</i> a) <i>Supply voltage supervision</i> The supply voltage is supervised. If it is below its specific threshold , the power stages are switched in tristate and the status flag is switched low. If the supply voltage is over the specific theshold again , the power stage switches independently into normal operation, according to the input pins and the status flag is reset . <i>b) Thermal supervision</i> In case of over-temperature the power stages are switched in tristate independent of the inputs signals and the status flag is switched low. If the level changes from high to low on D11 (IN1) or low to high on D12 ( IN2 ), the output stage switches on again if the temperature is below the specified limit .The status-flag is reset to high level (Pinnames in brackets refer to coding pin=Vcc). c) <i>Supervision of overcurrent</i> If overcurrent is detected the power stages are independent of the inputs signals switched in tristate and the status flag is set . If the level changes from high to low on D11 (IN1) or low to high on D12 ( IN2 ) the output stage switches on again and the status flag is reset to high level (Pinnames in brackets refer to coding pin=Vcc). c) <i>Supervision of overcurrent</i> If overcurrent is detected the power stages are independent of the inputs signals switched in tristate and the status flag is reset to high level (Pinnames in brackets refer to coding pin = Vcc). The output stage switches on again and the status flag is reset to high level (Pinnames in brackets refer to coding pin = Vcc). The output stage switches into the mode defined by the inputs pins provided the temperature is below the specified limits . <i>d) Current limiting</i> The maximum current which ca



Figure 1. Typical Application







## Figure 6 - Standby Current versus Temperature









Figure 7. VBAT Undervoltage versus Temperature

















## Figure 18. Output OFF Delay



Figure 20. Disable Delay Time



 E 2 μ5 2.00 V
 1.00 V
 1.

Figure 19. Output ON Delay

Figure 21. High side Overcurrent Detection



## **PACKAGE INFORMATION**

The HSOP20 package is designed for enhanced thermal performance. The particularity of this package is its copper baseplate on which the power die is soldered. The baseplate is soldered on a PCB to provide heat flow to the ambient and also to provide a large thermal capacitance.

Of course, the more copper area on the PCB, the better the power dissipation and transient behaviour.

We characterized the HSOP20 on a double side PCB. The bottom side area of the copper is 7.8  $cm^2$ . The top surface is 2.7  $cm^2$ , see Figure 22.





Top Side

Bottom Side

Figure 23. PHSOP20 Thermal Response



Figure 23 shows the thermal response with the device soldered on to the test PCB described on figure 22.

## **CASE OUTLINES**



NOTES:

- 1. CONTROLLING DIMENSION: MILLIMETER. 2. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
- Y14.5M, 1994. DATUM PLANE -H- IS LOCATED AT BOTTOM OF LEAD AND IS COINCIDENT WITH THE LEAD WHERE THE LEAD EXITS THE PLASTIC BODY AT THE BOTTOM OF THE PARTING LINE. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD 3.
- 4 PROTRUSION. ALLOWABLE PROTRUSION IS 0.150 PER SIDE. DIMENSIONS D AND E1 DO
- INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE -H-. DELETIVITURED AT UM PLANE -H-. DIMENSION 5 DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 TOTAL IN EXCESS OF THE 5 DIMENSION AT MAXIMUM MATERIAL 5
- CONDITION.
- CONDITION.
   CATUMS –A– AND –B– TO BE DETERMINED AT DATUM PLANE –H–.
   DIMENSION D DOES NOT INCLUDE TIEBAR
  - PROTRUSIONS. ALLOWABLE TIEBAR PROTRUSIONS ARE 0.150 PER SIDE. MILLIMETERS

DIM	MIN	MAX				
A	3.000	3.400				
A1	0.100	0.300				
A2	2.900	3.100				
A3	0.00	0.100				
D	15.800	16.000				
D1	11.700	12.600				
D2	0.900	1.100				
E	13.950	14.450				
E1	10.900	11.100				
E2	2.500	2.700				
E3	6.400	7.200				
E4	2.700	2.900				
L	0.840	1.100				
L1	0.350 BSC					
b	0.400	0.520				
b1	0.400	0.482				
C	0.230	0.320				
c1	0.230	0.280				
e	1.270 BSC					
h	_	1.100				
θ	0	8				
	0.000					

0.100

bbb

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